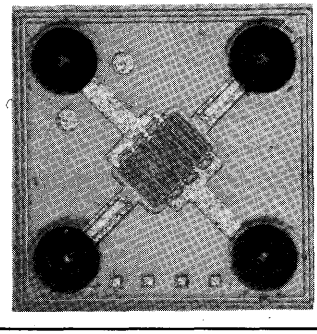
MMCF4223 (SILICON)
MMCF4224

FLIP-CHIP
N-CHANNEL JUNCTION
FIELD EFFECT
TRANSISTORS

Flip-Chip — N-channel junction field effect transistors designed for VHF amplifier and mixer applications.

- Drain and Source Interchangeable



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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	Vdc
Drain-Gate Voltage	V_{DG}	30	Vdc
Gate-Source Voltage	V_{GS}	30	Vdc
Drain Current	I_D	20	mAdc
Operating Junction Temperature	T_J	+175	°C

ELECTRICAL CHARACTERISTICS

Characteristic		Symbol	Min	Max	Unit
Gate-Source Breakdown Voltage (I_G = 10 μAdc, V_{DS} = 0)		$V_{(BR)GSS}$	30	–	Vdc
Gate Reverse Current		I_{GSS}			nAdc
(V_{GS} = 20 Vdc, V_{DS} = 0)	MMCF4223		–	0.5	
	MMCF4224		–	1.0	
Gate-Source Cutoff Voltage		$V_{GS(off)}$			Vdc
(V_{DS} = 15 Vdc, I_D = 0.5 nAdc)	MMCF4223		–	8.0	
(V_{DS} = 15 Vdc, I_D = 1.0 nAdc)	MMCF4224		–	8.0	
Gate-Source Voltage		V_{GS}			Vdc
(V_{DS} = 15 Vdc, I_D = 0.3 mAdc)	MMCF4223		1.0	7.0	
(V_{DS} = 15 Vdc, I_D = 0.2 mAdc)	MMCF4224		1.0	7.5	
Zero-Gate Voltage Drain Current		I_{DSS}			mAdc
(V_{DS} = 15 Vdc, V_{GS} = 0)	MMCF4223		3.0	18	
	MMCF4224		2.0	20	
Forward Transmittance		$\|y_{fs}\|$			μmhos
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 kHz)					
	MMCF4223		3000	7000	
	MMCF4224		2000	7500	
Input Capacitance (V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 MHz)		C_{iss}	–	8.0	pF
Reverse Transfer Capacitance (V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 MHz		C_{rss}	–	3.0	pF